NSN 5961-01-480-4024

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-480-4024 **Inclosure Material:** Plastic **Overall Length:** 3.0 millimeters **Overall Height:** 1.1 millimeters **Overall Width:** 2.5 millimeters **End Application:** Stv camera sy Joint Electronic Device Engineering Council/jedec/case Outline Designation: Sot-23 **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 50.0 working peak reverse voltage all semiconductor device diode **Current Rating Per Characteristic:** 200.00 milliamperes forward current, average absolute all semiconductor device diode and 600.00 milliamperes source cutoff current preset all semiconductor device diode **Power Rating Per Characteristic:** 350.0 milliwatts small-signal input power, common-collector preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Dual diode **Terminal Type And Quantity:** 3 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: